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(54) SEMICONDUCTOR DEVICE AND DISPLAY DEVICE

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(57)ABSTRACT

According to one embodiment, a semiconductor device includes a first gate electrode formed integrally with a scanning line, an oxide semiconductor layer, first and second signal lines which are in contact with the oxide semiconductor layer, and a second gate electrode provided so as to face the first gate electrode across the oxide semiconductor layer therebetween and connected to the first gate electrode. The second gate electrode is provided between the first signal line and the second signal line and does not overlap the first signal line or the second signal line.

